

LP3891 0.8A Fast-Response Ultra Low Dropout Linear Regulators

Check for Samples: [LP3891](#)

FEATURES

- Ultra Low Dropout Voltage (100mV at 0.8A typ)
- Low Ground Pin Current
- Load Regulation of 0.04%/A
- 60 nA Typical Quiescent Current in Shutdown
- 1.5% Output Accuracy (25°C)
- TO-220, DPAK/TO-263 and SO PowerPAD-8 Packages
- Over Temperature/Over Current Protection
- -40°C to +125°C Junction Temperature Range

APPLICATIONS

- DSP Power Supplies
- Server Core and I/O Supplies
- PC Add-in-Cards
- Local Regulators in Set-Top Boxes
- Microcontroller Power Supplies
- High Efficiency Power Supplies
- SMPS Post-Regulators

DESCRIPTION

The LP3891 is a high current, fast response regulator which can maintain output voltage regulation with minimum input to output voltage drop. Fabricated on a CMOS process, the device operates from two input voltages: Vbias provides voltage to drive the gate of the N-MOS power transistor, while Vin is the input voltage which supplies power to the load. The use of an external bias rail allows the part to operate from ultra low Vin voltages. Unlike bipolar regulators, the CMOS architecture consumes extremely low quiescent current at any output load current. The use of an N-MOS power transistor results in wide bandwidth, yet minimum external capacitance is required to maintain loop stability.

The fast transient response of these devices makes them suitable for use in powering DSP, Microcontroller Core voltages and Switch Mode Power Supply post regulators. The parts are available in TO-220, DPAK/TO-263 and SO PowerPAD-8 packages.

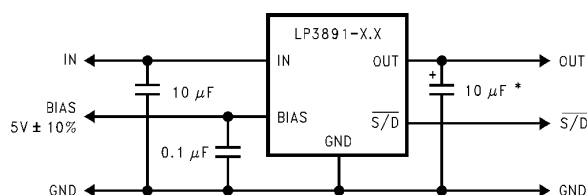
Dropout Voltage: 100 mV (typ) at 0.8A load current.

Ground Pin Current: 3 mA (typ) at full load.

Shutdown Current: 60 nA (typ) when S/D pin is low.

Precision Output Voltage: 1.5% room temperature accuracy.

TYPICAL APPLICATION CIRCUIT



At least 10 µF of input and output capacitance is required for stability.

*Tantalum capacitors are recommended. Aluminum electrolytic capacitors may be used for restricted temperature range. See application hints.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

CONNECTION DIAGRAM

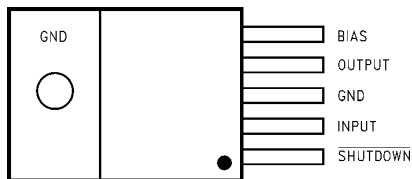


Figure 1. TO-220, Top View

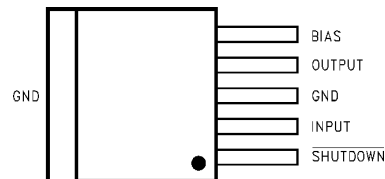


Figure 2. DDPAK/TO-263, Top View

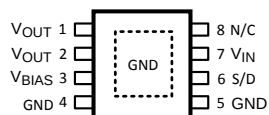
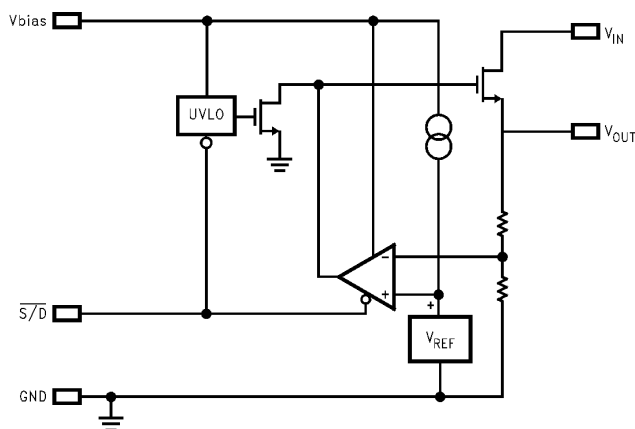


Figure 3. SO PowerPAD-8, Top View

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

If Military/Aerospace specified devices are required, contact the Texas Instruments Sales Office/Distributors for availability and specifications.

	VALUE / UNITS
Storage Temperature Range	–65°C to +150°C
Lead Temp. (Soldering, 5 seconds)	260°C
ESD Rating Human Body Model ⁽²⁾ Machine Model ⁽³⁾	2 kV 200V
Power Dissipation ⁽⁴⁾	Internally Limited
V _{IN} Supply Voltage (Survival)	–0.3V to +6V
V _{BIAS} Supply Voltage (Survival)	–0.3V to +7V
Shutdown Input Voltage (Survival)	–0.3V to +7V
I _{OUT} (Survival)	Internally Limited
Output Voltage (Survival)	–0.3V to +6V
Junction Temperature	–40°C to +150°C

- (1) Absolute maximum ratings indicate limits beyond which damage to the component may occur. Operating ratings indicate conditions for which the device is intended to be functional, but do **not** ensure specific performance limits. For specifications, see Electrical Characteristics. Specifications do not apply when operating the device outside of its rated operating conditions.
- (2) The human body model is a 100 pF capacitor discharged through a 1.5k resistor into each pin.
- (3) The machine model is a 220 pF capacitor discharged directly into each pin. The machine model ESD rating of pin 5 is 100V.
- (4) At elevated temperatures, device power dissipation must be derated based on package thermal resistance and heatsink thermal values. θ_{JA} for TO-220 devices is 65°C/W if no heatsink is used. If the TO-220 device is attached to a heatsink, a θ_{JS} value of 4°C/W can be assumed. θ_{JA} for TO-263 devices is approximately 40°C/W if soldered down to a copper plane which is at least 1.5 square inches in area. θ_{JA} value for typical SO PowerPAD-8 PC board mounting is 166°C/W. If power dissipation causes the junction temperature to exceed specified limits, the device will go into thermal shutdown.

RECOMMENDED OPERATING CONDITIONS

	VALUE / UNITS
V _{IN}	(V _{OUT} + V _{DO}) to 5.5V
Shutdown	0 to +6V
I _{OUT}	0.8A
Junction Temperature	–40°C to +125°C
V _{BIAS}	4.5V to 6V

ELECTRICAL CHARACTERISTICS

Limits in standard typeface are for $T_J = 25^\circ\text{C}$, and limits in **boldface type** apply over the full operating temperature range. Unless otherwise specified: $V_{IN} = V_{O(NOM)} + 1\text{V}$, $V_{BIAS} = 4.5\text{V}$, $I_L = 10\text{ mA}$, $C_{IN} = C_{OUT} = 10\text{ }\mu\text{F}$, $V_{S/D} = V_{BIAS}$.

Symbol	Parameter	Conditions	MIN ⁽¹⁾	Typical ⁽²⁾	MAX ⁽¹⁾	Units
V _O	Output Voltage Tolerance	10 mA ≤ I _L ≤ 0.8A, V _O (NOM) + 1V ≤ V _{IN} ≤ 5.5V, 4.5V ≤ V _{BIAS} ≤ 6V	1.198 1.186	1.216	1.234 1.246	V
			1.478 1.455	1.5	1.522 1.545	
			1.773 1.746	1.8	1.827 1.854	
ΔV _O /ΔV _{IN}	Output Voltage Line Regulation ⁽³⁾	V _O (NOM) + 1V ≤ V _{IN} ≤ 5.5V		0.01		%/V
ΔV _O /ΔI _L	Output Voltage Load Regulation ⁽⁴⁾ ⁽⁵⁾	10 mA ≤ I _L ≤ 0.8A		0.04 0.06		%/A
V _{DO}	Dropout Voltage ⁽⁶⁾	I _L = 0.8A (TO220 and TO263 only)		100	300 400	mV
		I _L = 0.8A (SO PowerPAD only)		115	320 430	
I _Q (V _{IN})	Quiescent Current Drawn from V _{IN} Supply	10 mA ≤ I _L ≤ 0.8A		3	7 8	mA
		V _{S/D} ≤ 0.3V		0.03	1 30	μA
I _Q (V _{BIAS})	Quiescent Current Drawn from V _{BIAS} Supply	10 mA ≤ I _L ≤ 0.8A		1	2 3	mA
		V _{S/D} ≤ 0.3V		0.03	1 30	μA
I _{SC}	Short-Circuit Current	V _{OUT} = 0V		2.5		A
Shutdown Input						
V _{SDT}	Output Turn-off Threshold	Output = ON	1.3	0.7		V
		Output = OFF		0.7	0.3	
T _d (OFF)	Turn-OFF Delay	R _{LOAD} X C _{OUT} << T _d (OFF)		20		μs
T _d (ON)	Turn-ON Delay	R _{LOAD} X C _{OUT} << T _d (ON)		15		
I _{S/D}	S/D Input Current	V _{S/D} =1.3V		1		μA
		V _{S/D} ≤ 0.3V		-1		
AC Parameters						
PSRR (V _{IN})	Ripple Rejection for V _{IN} Input Voltage	V _{IN} = V _{OUT} +1V, f = 120 Hz		80		dB
		V _{IN} = V _{OUT} + 1V, f = 1 kHz		65		
PSRR (V _{BIAS})	Ripple Rejection for V _{BIAS} Voltage	V _{BIAS} = V _{OUT} + 3V, f = 120 Hz		70		
		V _{BIAS} = V _{OUT} + 3V, f = 1 kHz		65		
	Output Noise Density	f = 120 Hz		1		μV/root-Hz
e _n	Output Noise Voltage	BW = 10 Hz – 100 kHz, V _{OUT} = 1.8V		150		μV (rms)
		BW = 300 Hz – 300 kHz, V _{OUT} = 1.8V		90		

(1) Limits are specified through testing, statistical correlation, or design.

(2) Typical numbers represent the most likely parametric norm for 25°C operation.

(3) Output voltage line regulation is defined as the change in output voltage from nominal value resulting from a change in input voltage.

(4) If used in a dual-supply system where the regulator load is returned to a negative supply, the output pin must be diode clamped to ground.

(5) Output voltage load regulation is defined as the change in output voltage from nominal value as the load current increases from no load to full load.

(6) Dropout voltage is defined as the minimum input to output differential required to maintain the output with 2% of nominal value. The SO PowerPAD-8 package devices have a slightly higher dropout voltage due to increased bond wire resistance.

TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified: $T_J = 25^\circ\text{C}$, $C_{OUT} = 10\ \mu\text{F}$, $C_{in} = 10\ \mu\text{F}$, $\overline{\text{S/D}}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2\text{V}$, $V_{OUT} = 1.8\text{V}$

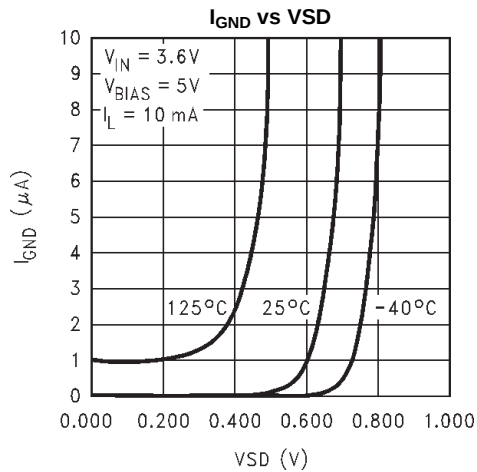


Figure 4.

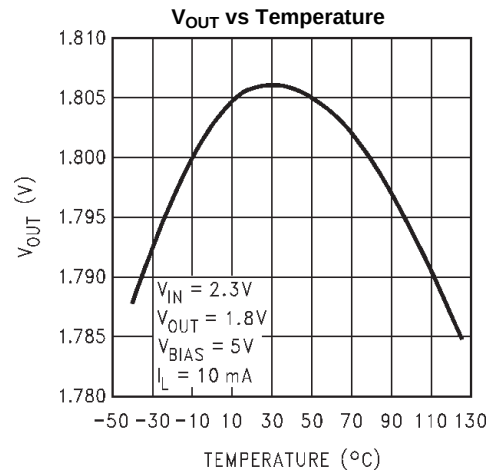


Figure 5.

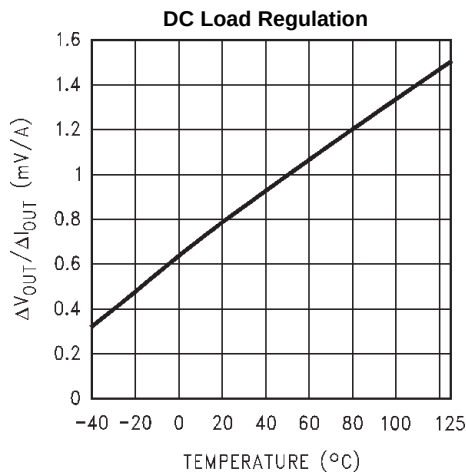


Figure 6.

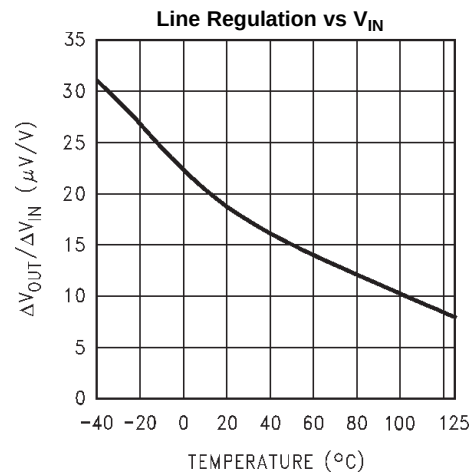


Figure 7.

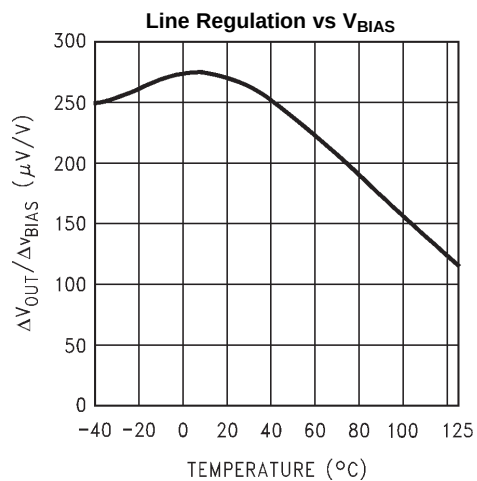


Figure 8.

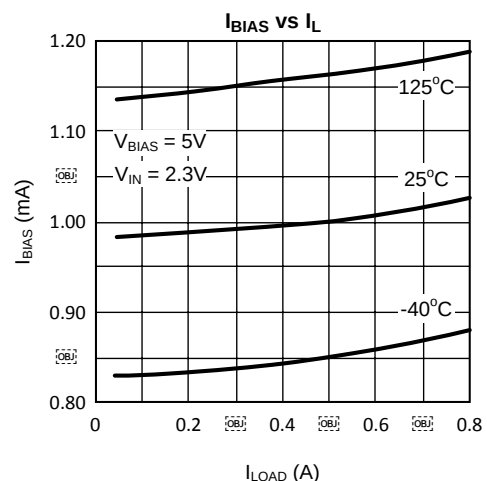


Figure 9.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: $T_J = 25^\circ\text{C}$, $C_{OUT} = 10\ \mu\text{F}$, $C_{IN} = 10\ \mu\text{F}$, $\overline{\text{S/D}}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2\text{V}$, $V_{OUT} = 1.8\text{V}$

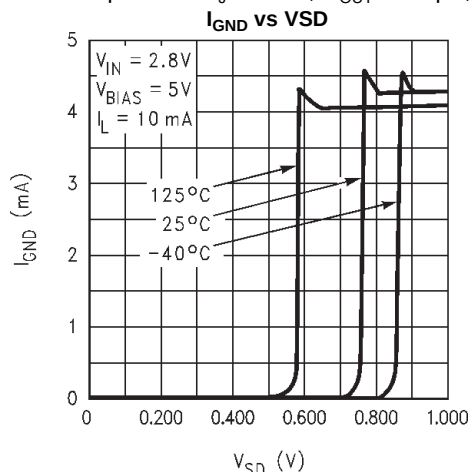


Figure 10.

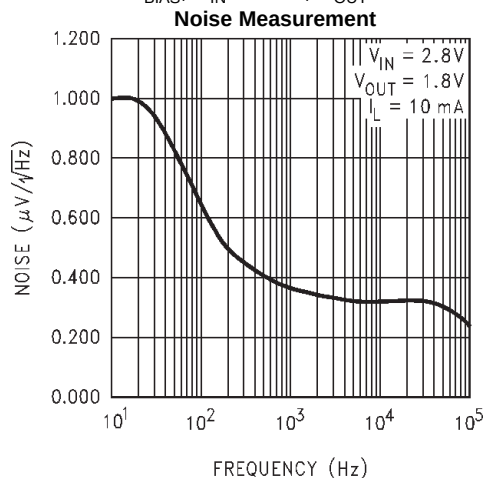


Figure 11.

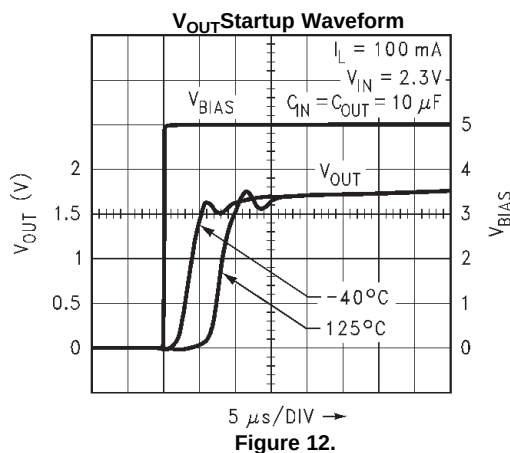


Figure 12.

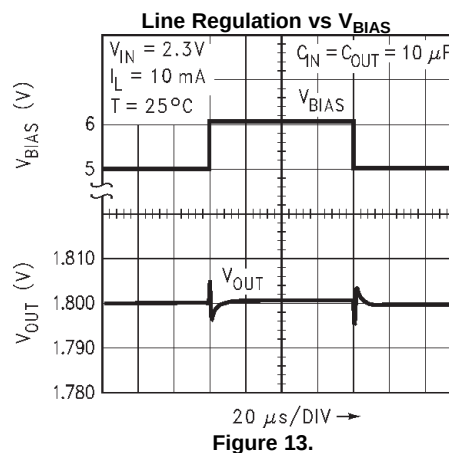


Figure 13.

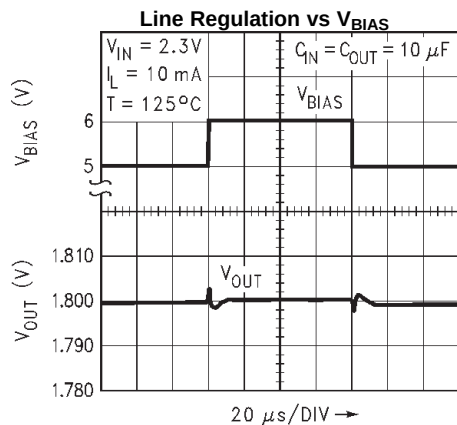


Figure 14.

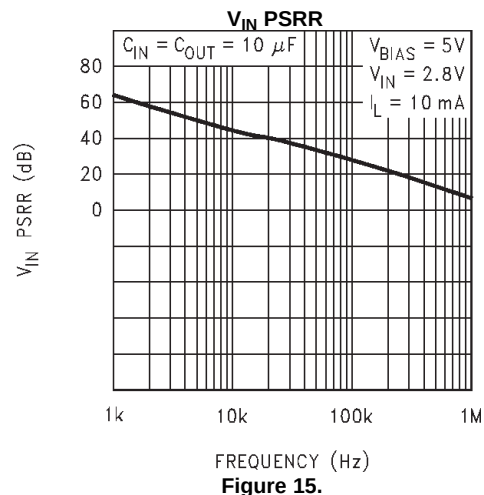


Figure 15.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: $T_J = 25^\circ\text{C}$, $C_{OUT} = 10\ \mu\text{F}$, $C_{IN} = 10\ \mu\text{F}$, $\overline{\text{S/D}}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2\text{V}$, $V_{OUT} = 1.8\text{V}$

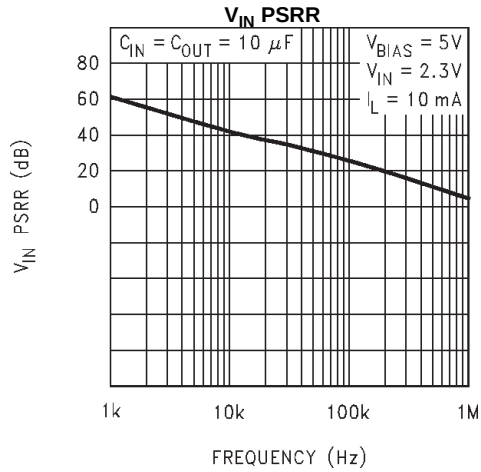


Figure 16.

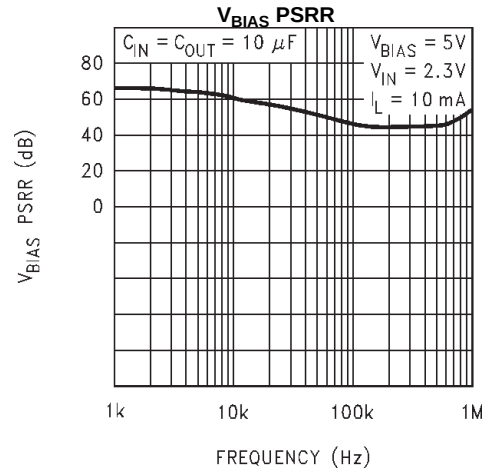


Figure 17.

Application Hints

EXTERNAL CAPACITORS

To assure regulator stability, input and output capacitors are required as shown in the Typical Application Circuit.

OUTPUT CAPACITOR

At least 10 μ F of output capacitance is required for stability (the amount of capacitance can be increased without limit). The output capacitor must be located less than 1cm from the output pin of the IC and returned to a clean analog ground. The ESR (equivalent series resistance) of the output capacitor must be within the "stable" range as shown in the graph below over the full operating temperature range for stable operation.

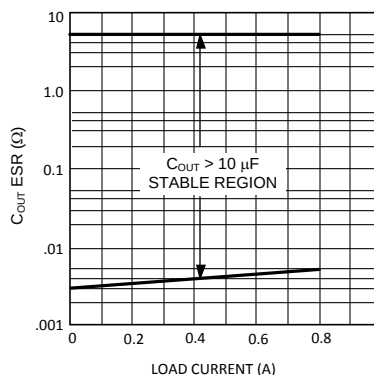


Figure 18. Minimum ESR vs Output Load Current

Tantalum capacitors are recommended for the output as their ESR is ideally suited to the part's requirements and the ESR is very stable over temperature. Aluminum electrolytics are not recommended because their ESR increases very rapidly at temperatures below 10°C. Aluminum caps can only be used in applications where lower temperature operation is not required.

A second problem with Al caps is that many have ESR's which are only specified at low frequencies. The typical loop bandwidth of a linear regulator is a few hundred kHz to several MHz. If an Al cap is used for the output cap, it must be one whose ESR is specified at a frequency of 100 kHz or more.

Because the ESR of ceramic capacitors is only a few milli Ohms, they are not suitable for use as output capacitors on LP389X devices. The regulator output can tolerate ceramic capacitance totaling up to 15% of the amount of Tantalum capacitance connected from the output to ground.

INPUT CAPACITOR

The input capacitor must be at least 10 μ F, but can be increased without limit. It's purpose is to provide a low source impedance for the regulator input. Ceramic capacitors work best for this, but Tantalums are also very good. There is no ESR limitation on the input capacitor (the lower, the better). Aluminum electrolytics can be used, but their ESR increase very quickly at cold temperatures. They are not recommended for any application where temperatures go below about 10°C.

BIAS CAPACITOR

The 0.1 μ F capacitor on the bias line can be any good quality capacitor (ceramic is recommended).

BIAS VOLTAGE

The bias voltage is an external voltage rail required to get gate drive for the N-FET pass transistor. Bias voltage must be in the range of 4.5 - 6V to assure proper operation of the part.

UNDER VOLTAGE LOCKOUT

The bias voltage is monitored by a circuit which prevents the regulator output from turning on if the bias voltage is below approximately 4V.

SHUTDOWN OPERATION

Pulling down the shutdown ($\overline{S/D}$) pin will turn-off the regulator. Pin $\overline{S/D}$ must be actively terminated through a pull-up resistor (10 k Ω to 100 k Ω) for a proper operation. If this pin is driven from a source that actively pulls high and low (such as a CMOS rail to rail comparator), the pull-up resistor is not required. This pin must be tied to Vin if not used.

POWER DISSIPATION/HEATSINKING

A heatsink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible conditions, the junction temperature must be within the range specified under operating conditions. The total power dissipation of the device is given by:

$$P_D = (V_{IN} - V_{OUT})I_{OUT} + (V_{IN})I_{GND} \quad (1)$$

where I_{GND} is the operating ground current of the device.

The maximum allowable temperature rise (T_{Rmax}) depends on the maximum ambient temperature (T_{Amax}) of the application, and the maximum allowable junction temperature (T_{Jmax}):

$$T_{Rmax} = T_{Jmax} - T_{Amax} \quad (2)$$

The maximum allowable value for junction to ambient Thermal Resistance, θ_{JA} , can be calculated using the formula:

$$\theta_{JA} = T_{Rmax} / P_D \quad (3)$$

These parts are available in TO-220 and DDPAK/TO-263 packages. The thermal resistance depends on amount of copper area or heat sink, and on air flow. If the maximum allowable value of θ_{JA} calculated above is ≥ 60 °C/W for TO-220 package and ≥ 60 °C/W for DDPAK/TO-263 package no heatsink is needed since the package can dissipate enough heat to satisfy these requirements. If the value for allowable θ_{JA} falls below these limits, a heat sink is required.

HEATSINKING TO-220 PACKAGE

The thermal resistance of a TO-220 package can be reduced by attaching it to a heat sink or a copper plane on a PC board. If a copper plane is to be used, the values of θ_{JA} will be same as shown in next section for DDPAK/TO-263 package.

The heatsink to be used in the application should have a heatsink to ambient thermal resistance,

$$\theta_{HA} \leq \theta_{JA} - \theta_{CH} - \theta_{JC} \quad (4)$$

In this equation, θ_{CH} is the thermal resistance from the case to the surface of the heat sink and θ_{JC} is the thermal resistance from the junction to the surface of the case. θ_{JC} is about 3°C/W for a TO220 package. The value for θ_{CH} depends on method of attachment, insulator, etc. θ_{CH} varies between 1.5°C/W to 2.5°C/W. If the exact value is unknown, 2°C/W can be assumed.

HEATSINKING DDPAK/TO-263 PACKAGE

The DDPAK/TO-263 package uses the copper plane on the PCB as a heatsink. The tab of these packages are soldered to the copper plane for heat sinking. [Figure 19](#) shows a curve for the θ_{JA} of DDPAK/TO-263 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat sinking.

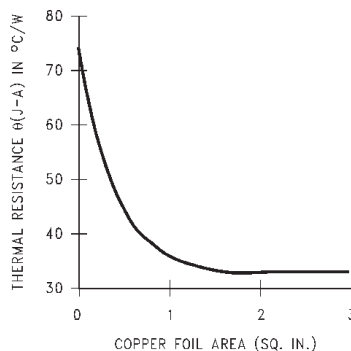


Figure 19. θ_{JA} vs Copper (1 Ounce) Area for DDPAK/TO-263 Package

As shown in [Figure 20](#), increasing the copper area beyond 1 square inch produces very little improvement. The minimum value for θ_{JA} for the DDPAK/TO-263 package mounted to a PCB is 32°C/W.

[Figure 20](#) shows the maximum allowable power dissipation for DDPAK/TO-263 packages for different ambient temperatures, assuming θ_{JA} is 35°C/W and the maximum junction temperature is 125°C.

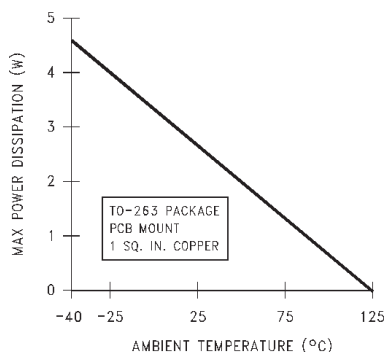


Figure 20. Maximum Power Dissipation vs Ambient Temperature for DDPAK/TO-263 Package

HEATSINKING SO PowerPAD PACKAGE

Heatsinking for the SO PowerPAD-8 package is accomplished by allowing heat to flow through the ground slug on the bottom of the package into the copper on the PC board. The heat slug must be soldered down to a copper plane to get good heat transfer. It can also be connected through vias to internal copper planes. Since the heat slug is at ground potential, traces must not be routed under it which are not at ground potential. Under all possible conditions, the junction temperature must be within the range specified under operating conditions.

[Figure 21](#) shows a curve for the θ_{JA} of the SO PowerPAD package for different copper area sizes using a typical PCB with one ounce copper in still air.

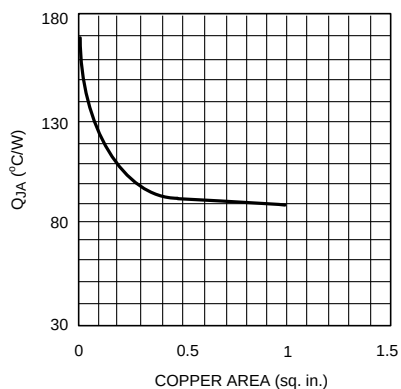


Figure 21. θ_{JA} vs Copper (1 ounce) Area for SO PowerPAD Package

REVISION HISTORY

Changes from Revision C (April 2013) to Revision D

Page

- Changed layout of National Data Sheet to TI format [11](#)

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LP3891EMR-1.2/NOPB	Active	Production	SO PowerPAD (DDA) 8	95 TUBE	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.2
LP3891EMR-1.2/NOPB.A	Active	Production	SO PowerPAD (DDA) 8	95 TUBE	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.2
LP3891EMR-1.8/NOPB	Active	Production	SO PowerPAD (DDA) 8	95 TUBE	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.8
LP3891EMR-1.8/NOPB.A	Active	Production	SO PowerPAD (DDA) 8	95 TUBE	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.8
LP3891EMRX-1.2/NO.A	Active	Production	SO PowerPAD (DDA) 8	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.2
LP3891EMRX-1.2/NOPB	Active	Production	SO PowerPAD (DDA) 8	2500 LARGE T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	3891E MR1.2
LP3891ES-1.2/NOPB	Active	Production	DDPAK/ TO-263 (KTT) 5	45 TUBE	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.2
LP3891ES-1.2/NOPB.A	Active	Production	DDPAK/ TO-263 (KTT) 5	45 TUBE	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.2
LP3891ES-1.5/NOPB	Active	Production	DDPAK/ TO-263 (KTT) 5	45 TUBE	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.5
LP3891ES-1.5/NOPB.A	Active	Production	DDPAK/ TO-263 (KTT) 5	45 TUBE	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.5
LP3891ESX-1.2/NOPB	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.2
LP3891ESX-1.2/NOPB.A	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.2
LP3891ESX-1.5/NOPB	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.5
LP3891ESX-1.5/NOPB.A	Active	Production	DDPAK/ TO-263 (KTT) 5	500 LARGE T&R	ROHS Exempt	SN	Level-3-245C-168 HR	-40 to 125	LP3891ES -1.5

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

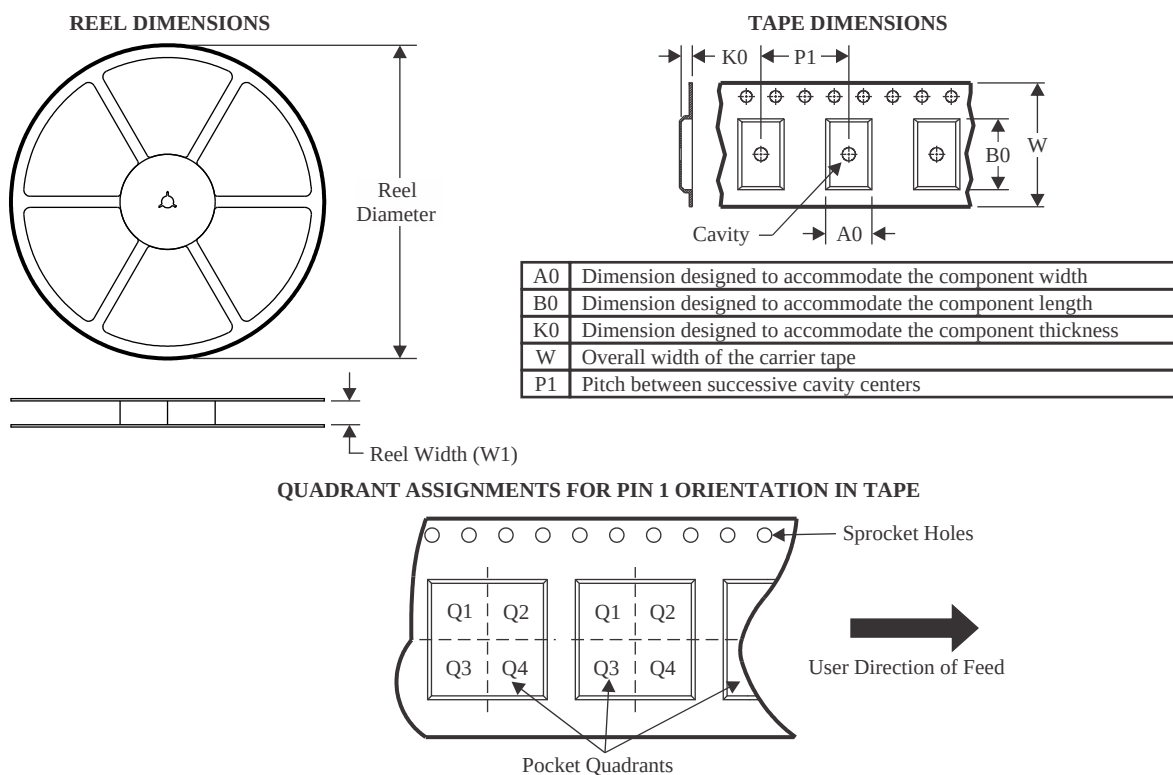
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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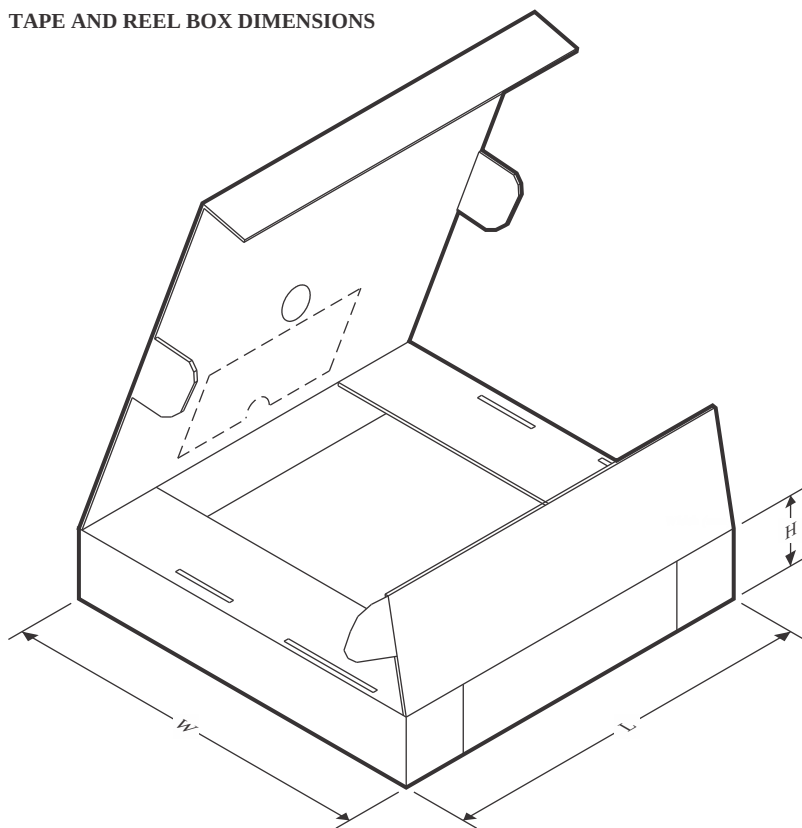
TAPE AND REEL INFORMATION



*All dimensions are nominal

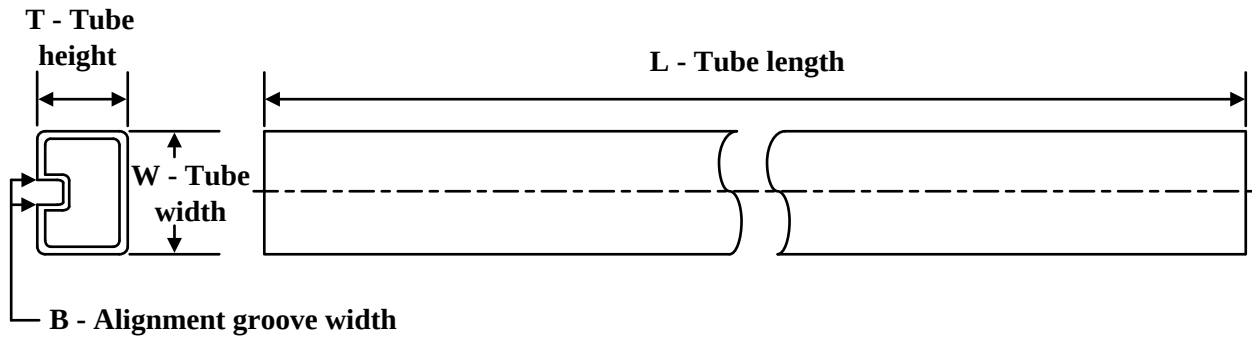
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP3891EMRX-1.2/NOPB	SO PowerPAD	DDA	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LP3891ESX-1.2/NOPB	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2
LP3891ESX-1.5/NOPB	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP3891EMRX-1.2/NOPB	SO PowerPAD	DDA	8	2500	356.0	356.0	36.0
LP3891ESX-1.2/NOPB	DDPAK/TO-263	KTT	5	500	356.0	356.0	45.0
LP3891ESX-1.5/NOPB	DDPAK/TO-263	KTT	5	500	356.0	356.0	45.0

TUBE


*All dimensions are nominal

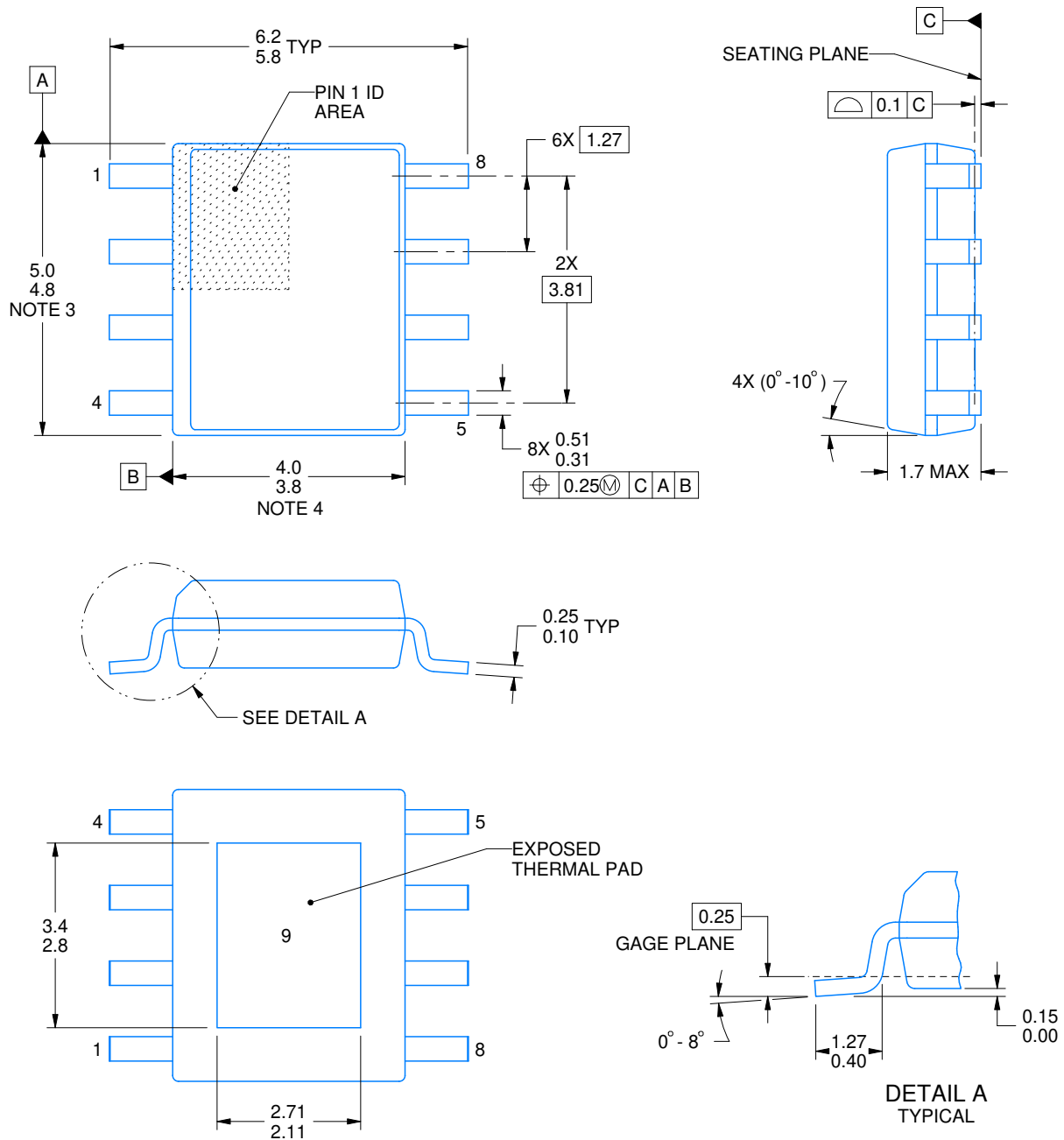
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LP3891EMR-1.2/NOPB	DDA	HSOIC	8	95	495	8	4064	3.05
LP3891EMR-1.2/NOPB.A	DDA	HSOIC	8	95	495	8	4064	3.05
LP3891EMR-1.8/NOPB	DDA	HSOIC	8	95	495	8	4064	3.05
LP3891EMR-1.8/NOPB.A	DDA	HSOIC	8	95	495	8	4064	3.05
LP3891ES-1.2/NOPB	KTT	TO-263	5	45	502	25	8204.2	9.19
LP3891ES-1.2/NOPB.A	KTT	TO-263	5	45	502	25	8204.2	9.19
LP3891ES-1.5/NOPB	KTT	TO-263	5	45	502	25	8204.2	9.19
LP3891ES-1.5/NOPB.A	KTT	TO-263	5	45	502	25	8204.2	9.19

DDA0008B

PACKAGE OUTLINE

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



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NOTES:

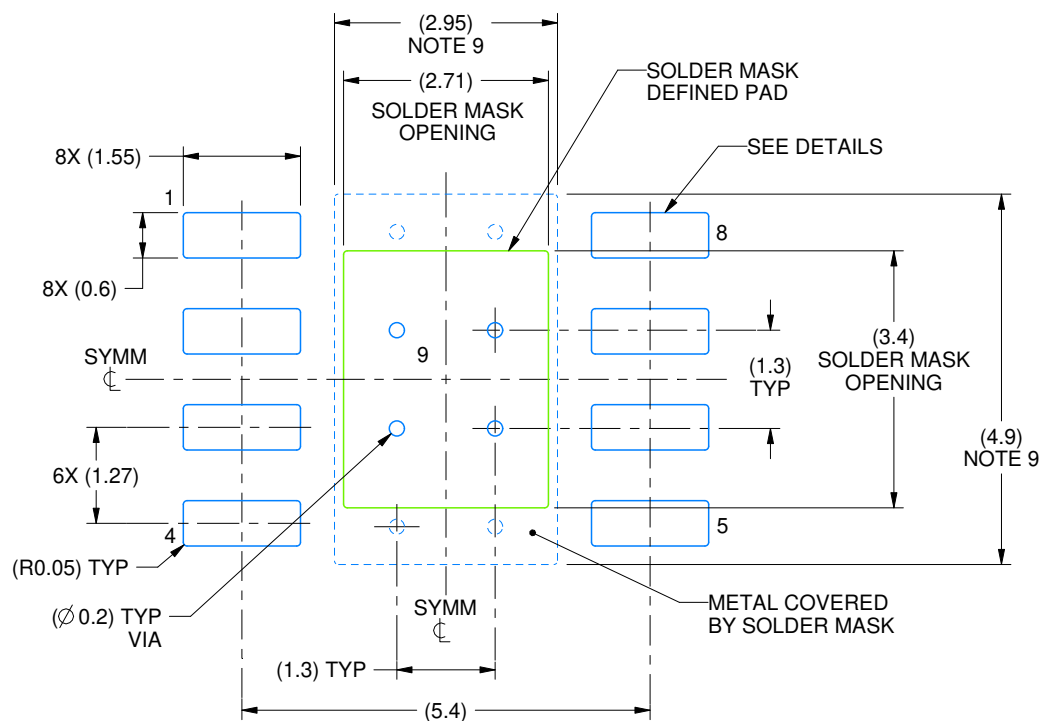
PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MS-012.

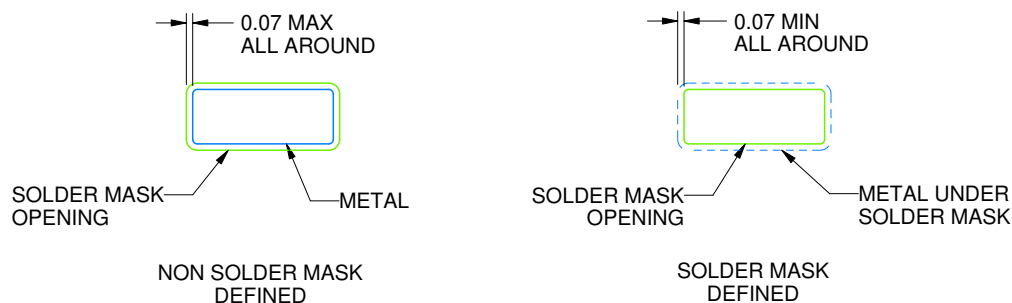
DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS

PADS 1-8

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NOTES: (continued)

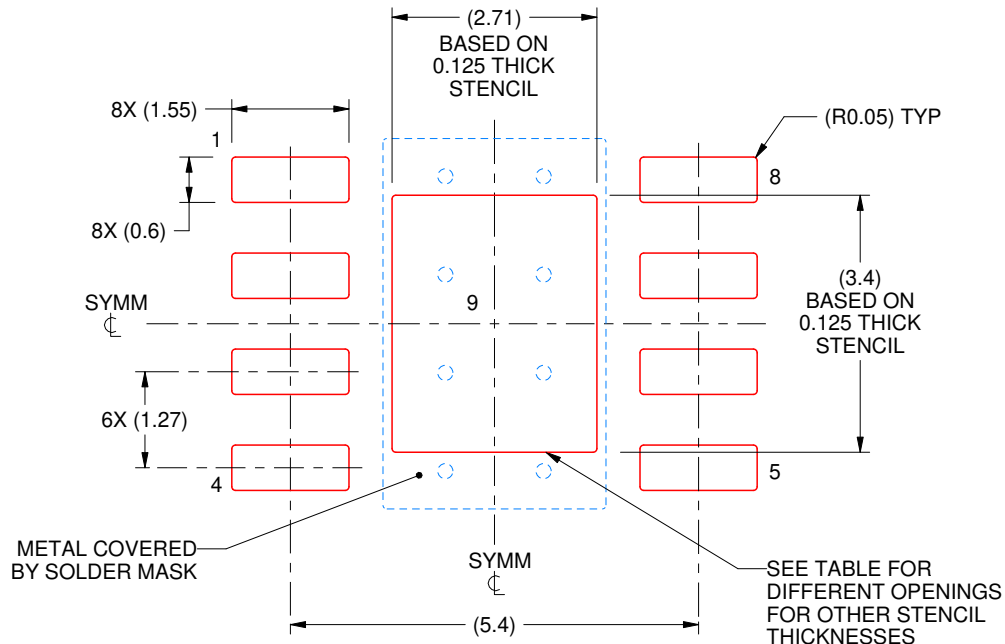
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.
10. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DDA0008B

PowerPAD™ SOIC - 1.7 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.03 X 3.80
0.125	2.71 X 3.40 (SHOWN)
0.150	2.47 X 3.10
0.175	2.29 X 2.87

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NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.



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